



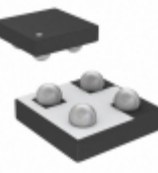






	<h2>SI8802DB-T2-E1</h2>
	<p>Hersteller-Teilenummer: SI8802DB-T2-E1</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 8V MICROFOOT</p> <p>Datenblätter:  SI8802DB-T2-E1.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 970 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI8802DB-T2-E1
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 8V MICROFOOT
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	970 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	4-XFBGA
Supplier Device-Gehäuse	4-Microfoot
Verlustleistung (max)	500mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	8V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-
Rds On (Max) @ Id, Vgs	54 mOhm @ 1A, 4.5V
VGS (th) (Max) @ Id	700mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	6.5nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	1.2V, 4.5V
Vgs (Max)	±5V
Verpackung	Tape & Reel (TR)



















































SI8802DB-T2-E1 ist neu im Original, Suche SI8802DB-T2-E1 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI8802DB-T2-E1 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI8802DB-T2-E1: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI87XXSDIP6-KIT Energy Micro (Silicon Labs) KIT EVAL SI871X SO-6</p>	 <p>SI8800EDB-T2-E1 Vishay / Siliconix MOSFET N-CH 20V MICROFOOT</p>	 <p>SI8805EDB-T2-E1 Electro-Films (EFI) / Vishay MOSFET P-CH 8V MICROFOOT</p>	 <p>SI87XXSOIC8-KIT Energy Micro (Silicon Labs) KIT EVAL GW 8SOIC SI871X</p>
 <p>SI8806DB-T2-E1 Vishay / Siliconix MOSFET N-CH 12V MICROFOOT</p>	 <p>SI8806DB-T2-E1 Electro-Films (EFI) / Vishay MOSFET N-CH 12V MICROFOOT</p>	 <p>SI8802DB-T2-E1 Electro-Films (EFI) / Vishay MOSFET N-CH 8V MICROFOOT</p>	 <p>SI8805EDB-T2-E1 Vishay / Siliconix MOSFET P-CH 8V MICROFOOT</p>

heiße Teile

Mehr

 SI8640EC-B-IS	 SI8640ED-B-IS	 SI8641BB-B-IS	 SI8641BC-B-IS	 SI8641BD-A-ISR
 SI8641BD-B-IS	 SI8641BD-B-ISR	 SI8641EC-B-IS	 SI8641ED-B-IS	 SI8641ED-B-ISR
 SI8642AB-B-ISR	 SI8642BC-B-IS1	 SI8645BB-B-IS	 SI8645BC-B-IS	 SI8645BD-B-IS
 SI8660AB-B-IS1	 SI8660BA-A-IS1R	 SI8661BD-B-ISR	 SI8662AB-B-IS1	 SI8662BC-A-IS1R
 SI8710AC-B-IS	 SI8710AD-B-IS	 SI8710BD	 SI8710CC-B-IP	 SI8710CC-B-IS
 SI8710CD-B-IS	 SI8710CD-B-ISR	 SI8711CC-B-IS	 SI8712AC-B-IS	 SI8716BC
 SI8716BC-A-IS	 SI8719BD-A-IS	 SI8800EDB-T2-E1	 SI8800EDB-T2-E1	 SI8802DB-T2-E1
 SI8808DB-T2-E1	 SI8808DB-T2-E1	 SI8812DB-T2-E1	 SI8812DB-T2-E1	 SI8901EDB-T2
 SI8901EDB-T2-E1	 SI8901EDB-T2-E1	 SI8902EDB	 SI8902EDB-T2	 SI8902EDB-T2-E
 SI8902EDB-T2-E1	 SI8902EDB-T2-E1	 SI8920AC-IP	 SI8920BC-IPR	 SI8920BC-IPR

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